

## Supporting Information

### **No hysteresis TIPS-pentacene:polystyrene Blend-based Organic Field Effect Transistor by Extruded Direct Ink Writing and the Application in Resistive Load Inverter Circuit**

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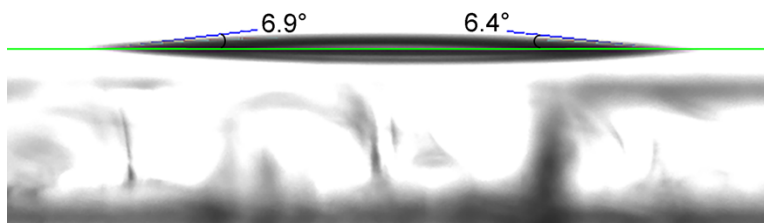


Fig. S-1 Toluene contact angles on Parylene dix-SR surface.

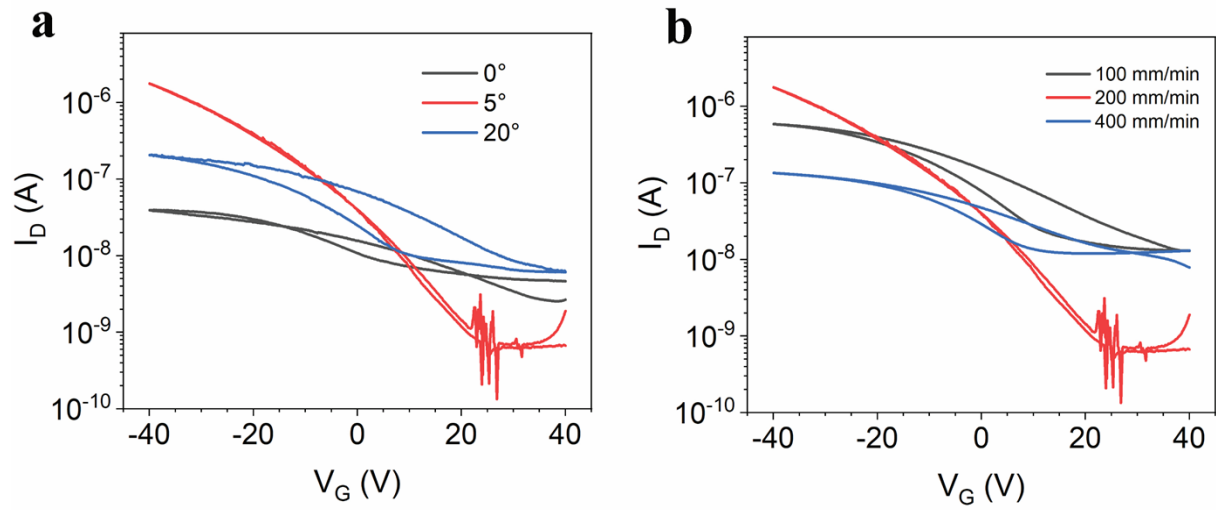


Fig. S-2 The transfer curves of OFETs with (a) different tilted substrates and (b) different printing speeds.

Table S-1. The electrical performance of OFET with different OSC deposition techniques including our work and previous studies.

Technique	Threshold voltage (V)	Maximum Mobility ( $\text{cm}^2 \text{V}^{-1} \text{s}^{-1}$ )	$I_{\text{ON}}/I_{\text{OFF}}$	Ref.
Spun-cast	-10	0.40	$6.0 \times 10^6$	1
Inkjet-printed	-20.40	0.064	$2.80 \times 10^4$	2
Ultrasonically-based printed	-	0.142	-	3
Spray-coated	-5.2	0.22	$3.32 \times 10^4$	4
Blade coated	-8.59	1.74	$1.45 \times 10^9$	5
Drop-casted	21.86	1.00	$3.30 \times 10^3$	This work
Motor-controlled Extrusion-based printed	1.46	0.14	$2.70 \times 10^3$	This work

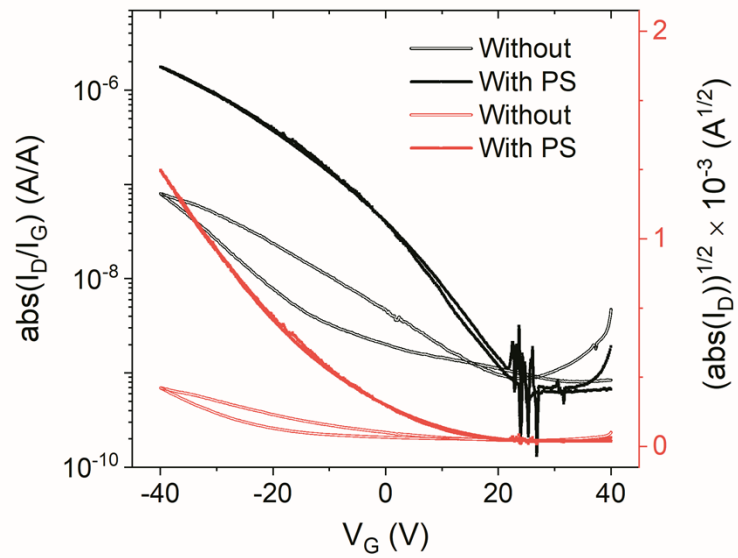


Fig. S-3 The transfer curves of OFETs with and without PS as an active layer.

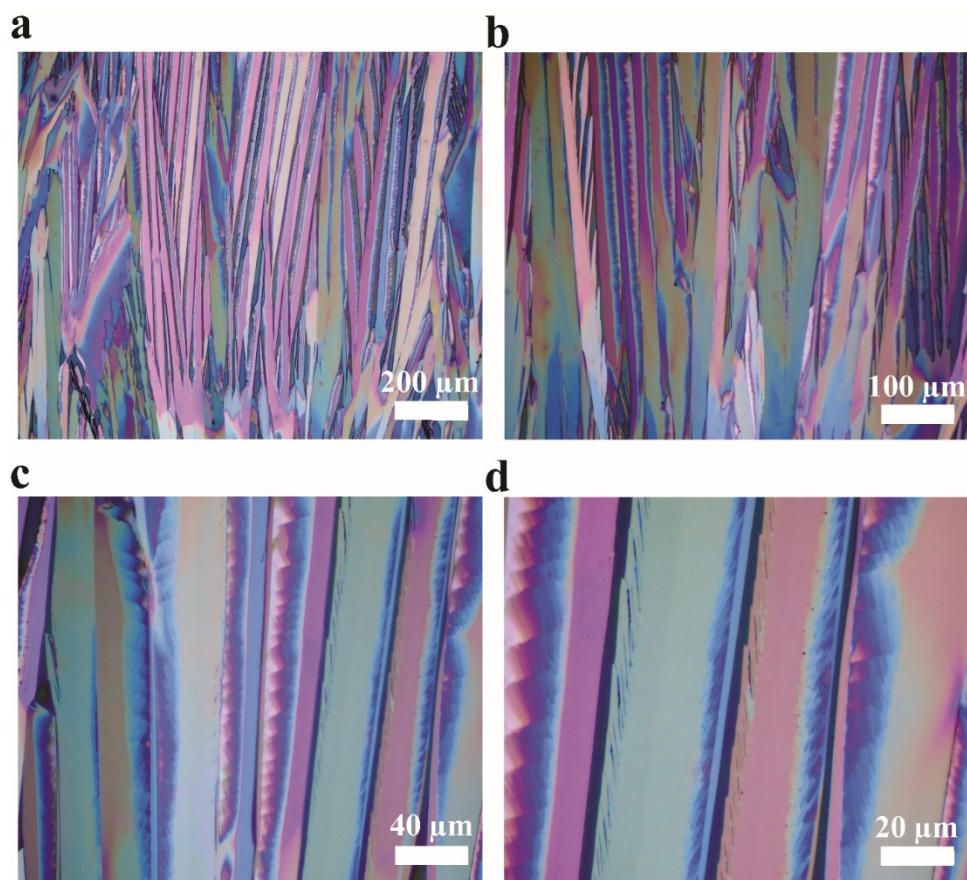


Fig. S-4 Polarized (75 degrees) optical microscope images of TIPS-pentacene:PS blend films with 25 °C in-situ annealing temperature (a) 200  $\mu\text{m}$  (b) 100  $\mu\text{m}$  (c) 40  $\mu\text{m}$  (d) 20  $\mu\text{m}$ .

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